INTEGRATED CIRCUITS

DATA SHEET

74LVT16374A

3.3V LVT 16-bit edge-triggered D-type flip-flop (3-State)

Product specification
Supersedes data of 1998 Feb 19
IC23 Data Handbook





Philips Semiconductors Product specification

3.3V 16-bit edge-triggered D-type flip-flop (3-State)

74LVT16374A

FEATURES

- 16-bit edge-triggered flip-flop
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up reset
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74LVT16374A is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is a 16-bit edge-triggered D-type flip-flop featuring non-inverting 3-State outputs. The device can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CP), the Q outputs of the flip-flop take on the logic levels set up at the D inputs.

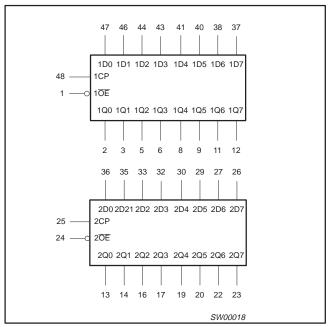
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	$C_L = 50pF;$ $V_{CC} = 3.3V$	2.9	ns
C _{IN}	Input capacitance	$V_I = 0V \text{ or } 3.0V$	3	pF
C _{OUT}	Output pin capacitance	Outputs disabled; $V_O = 0V$ or 3.0V	9	pF
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	70	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16374A DL	VT16374A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16374A DGG	VT16374A DGG	SOT362-1

LOGIC SYMBOL

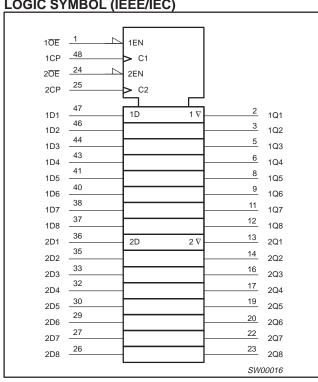


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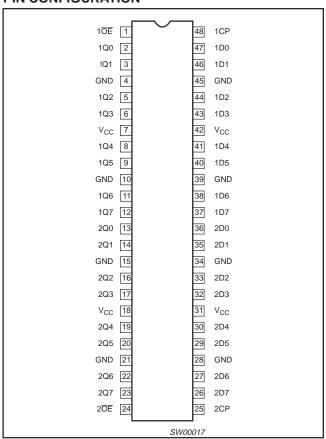
LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
47, 46, 44, 43, 41, 40, 38, 37 36, 35, 33, 32, 30, 29, 27, 26	1D0 - 1D7 2D0 - 2D7	Data inputs
2, 3, 5, 6, 8, 9, 11, 12 13, 14, 16, 17, 19, 20, 22, 23	1Q0 - 1Q7 2Q0 - 2Q7	Data outputs
1, 24	10E, 20E	Output enable inputs (active-Low)
48, 25	1CP, 2CP	Clock pulse inputs (active rising edge)
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

PIN CONFIGURATION



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FUNCTION TABLE

	INPUTS		INTERNAL	OUTPUTS	OPERATING MODE			
nOE	nCP	nDx	REGISTER	nQ0 - nQ7	OF ERATING MODE			
L L	↑	l h	L H	L H	Load and read register			
L	1	Х	NC	NC	Hold			
H H	↑	X nDx	NC nDx	Z Z	Disable outputs			

H = High voltage level

h = High voltage level one set-up time prior to the High-to-Low E transition

L = Low voltage level

= Low voltage level one set-up time prior to the High-to-Low E transition

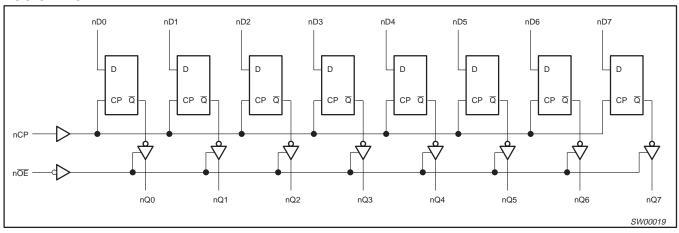
NC= No change

X = Don't care

Z = High impedance "off" state ↑ = Low-to-High clock transition

↑ = Not a Low-to-High clock transition

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	PARAMETER CONDITIONS				
V _{CC}	DC supply voltage		-0.5 to +4.6	V		
I _{IK}	DC input diode current	V _I < 0	-50	mA		
VI	DC input voltage ³		-0.5 to +7.0	V		
I _{OK}	DC output diode current	V _O < 0	-50	mA		
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V		
l	Output in Low state		128	mA		
lout	DC output current	Output in High state	-64			
T _{stg}	Storage temperature range		-65 to +150	°C		

NOTES:

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBOL	TANAMETER	MIN	MAX	ONIT
V _{CC}	DC supply voltage	2.7	3.6	V
V _I	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
la	Low-level output current		32	mA
lor	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	III/A
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

				1	LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			85	-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V _{CC} -0.2	V _{CC}		
V_{OH}	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.07	0.2	
		$V_{CC} = 2.7V; I_{OL} = 24mA$			0.3	0.5	
V_{OL}	Low-level output voltage	$V_{CC} = 3.0V; I_{OL} = 16mA$			0.25	0.4	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.3	0.5	
		$V_{CC} = 3.0V; I_{OL} = 64mA$	$V_{CC} = 3.0V; I_{OL} = 64mA$				
V _{RST}	Power-up output Low voltage ⁵	$V_{CC} = 3.6V$; $I_O = 1mA$; $V_I = GND$ or V_{CC}			0.1	0.55	V
		$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins	ol pins		±1	
ı	Input lookage ourrent	$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$			0.4	10	μΑ
łı	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$	Data pins ⁴		0.1	1	μΛ
		$V_{CC} = 3.6V; V_I = 0$	Data pins		-0.4	-5	
l _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			0.1	±100	μΑ
		$V_{CC} = 3V; V_{I} = 0.8V$	75	135			
I _{HOLD}	Bus Hold current D inputs ⁷	$V_{CC} = 3V; V_{I} = 2.0V$	-75	-135		μΑ	
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$	±500			1	
I _{EX}	Current into an output in the High state when V _O > V _{CC}	$V_O = 5.5V; V_{CC} = 3.0V$			50	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = GNE$ OE/ $\overline{OE} = Don't$ care	or V _{CC} ;		1	±100	μΑ
I _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IH} \text{ or } V_{IL}$			0.5	5	
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IH} \text{ or } V_{IL}$		0.5	-5	μΑ	
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or		0.07	0.12	mA	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or $V_{CC} = 3.6V$		4	6		
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GNE$	O or V_{CC} , $I_{O} = 0^6$		0.07	0.12	
Δl _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6V Other inputs at V_{CC} or GND	<i>I</i> ,		0.1	0.2	mA

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
- This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100μsec is permitted. This parameter is valid for T_{amb} = 25°C only.
 Unused pins at V_{CC} or GND.
- For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.
 I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
 This is the bus hold overdrive current required to force the input to the opposite logic state.

3.3V 16-bit edge-triggered D-type flip-flop (3-State)

74LVT16374A

AC CHARACTERISTICS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

SYMBOL	PARAMETER	WAVEFORM	$V_{CC} = 3.3V \pm 0.3V$			V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
f _{max}	Maximum clock frequency	1	150				MHz
t _{PLH} t _{PHL}	Propagation delay nCP to nQx	1	1.5 1.5	2.9 3.0	5.0 5.0	5.6 5.6	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	3 4	1.5 1.5	3.2 3.0	4.8 4.6	6.0 5.2	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	3 4	1.5 1.5	3.9 3.4	5.4 4.6	6.0 5.0	ns

NOTE:

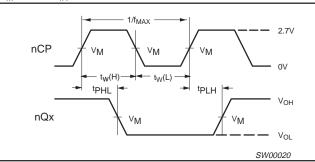
AC SETUP REQUIREMENTS

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

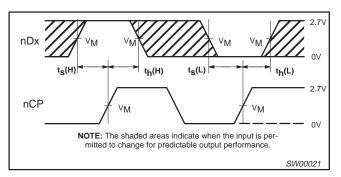
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 3.3	3V ±0.3V	V _{CC} = 2.7V	UNIT
			MIN	TYP	MIN	
t _S (H) t _S (L)	Setup time nDx to nCP	2	2.5 2.5	0.7 0.7	2.5 2.5	ns
t _h (H) t _h (L)	Hold time nDx to nCP	2	0.5 0.5	0 0	0 0	ns
t _W (H) tw(L)	nCP pulse width High or Low	1	1.5 3.0	0.6 1.6	1.5 3.0	ns

AC WAVEFORMS

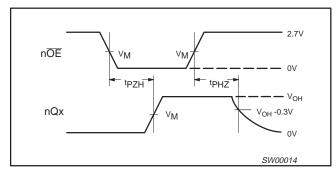
 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$



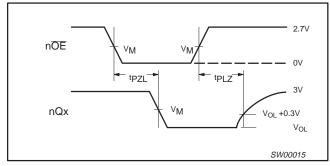
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



Waveform 2. Data Setup and Hold Times



Waveform 3. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 4. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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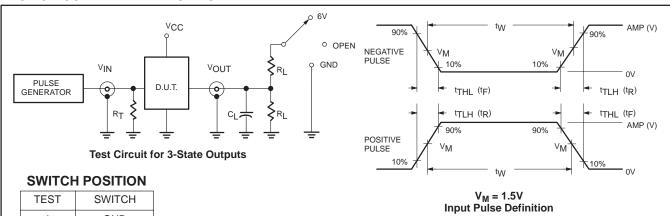
^{1.} All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25$ °C.

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TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PHZ} /t _{PZH}	GND
t _{PLZ} /t _{PZL}	6V
t _{PLH} /t _{PHL}	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$ capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T = \quad \text{Termination resistance should be equal to Z_{OUT} of pulse generators.}$

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

SW00003

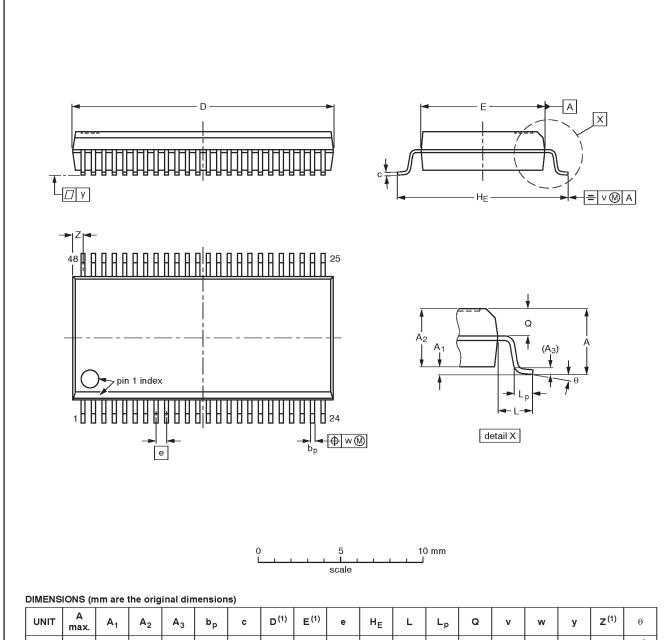
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3.3V LVT 16-bit edge-triggered D-type flip-flop (3-State)

74LVT16374A

SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

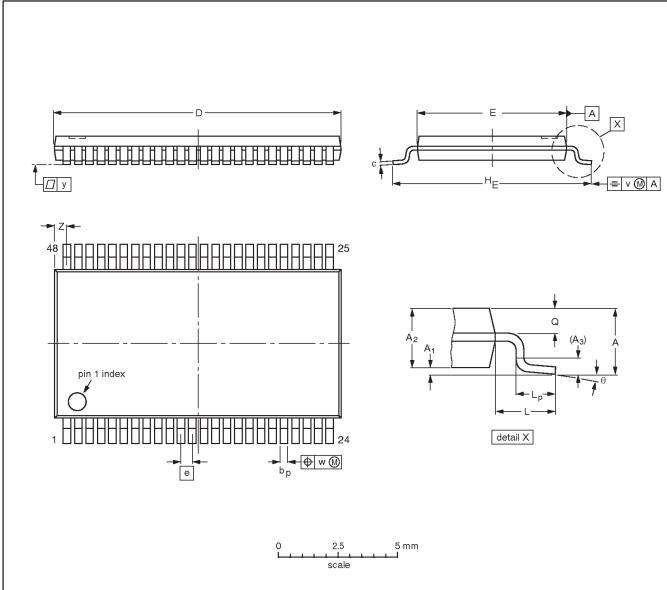
OUTLINE		REFER	EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT370-1		MO-118AA				93-11-02 95-02-04

3.3V LVT 16-bit edge-triggered D-type flip-flop (3-State)

74LVT16374A

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



DIMENSIONS (mm are the original dimensions).

UNIT	A max.	Α1	A ₂	А3	bp	c	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	œ	v	w	у	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT362-1		MO-153ED				-93-02-03 95-02-10

3.3V LVT 16-bit edge-triggered D-type flip-flop (3-State)

74LVT16374A

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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print code Date of release: 10-99

Document order number: 9397-750-06514

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